8-bit parallel-in/serial out shift register Rev. 2 — 9 August 2021

**Product data sheet** 

### 1. General description

The 74HC166-Q100; 74HCT166-Q100 is an 8-bit serial or parallel-in/serial-out shift register. The device features a serial data input (DS), eight parallel data inputs (D0 to D7) and a serial output (Q7). When the parallel enable input (PE) is LOW, the data from D0 to D7 is loaded into the shift register on the next LOW-to-HIGH transition of the clock input (CP). When PE is HIGH, data enters the register serially at DS with each LOW-to-HIGH transition of CP. When the clock enable input ( $\overline{CE}$ ) is LOW data is shifted on the LOW-to-HIGH transitions of CP. A HIGH on  $\overline{CE}$  disables the CP input. Inputs include clamp diodes which enable the use of current limiting resistors to interface inputs to voltages in excess of V<sub>CC</sub>.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)

  Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Synchronous parallel-to-serial applications
- Synchronous serial input for easy expansion
- Input levels:
  - For 74HC166-Q100: CMOS level
  - For 74HCT166-Q100: TTL level
- Complies with JEDEC standards:
  - JESD8C (2.7 V to 3.6 V)
  - JESD7A (2.0 V to 6.0 V)
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

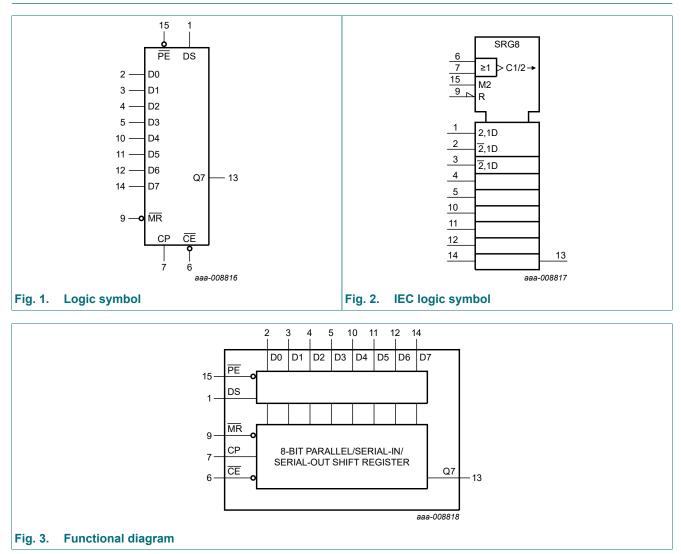
### 3. Ordering information

#### Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74HC166D-Q100	-40 °C to +125 °C	SO16	- France France Frances, 19, 19, 19, 19, 19, 19, 19, 19, 19, 19					
74HCT166D-Q100			body width 3.9 mm					
74HC166PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1				

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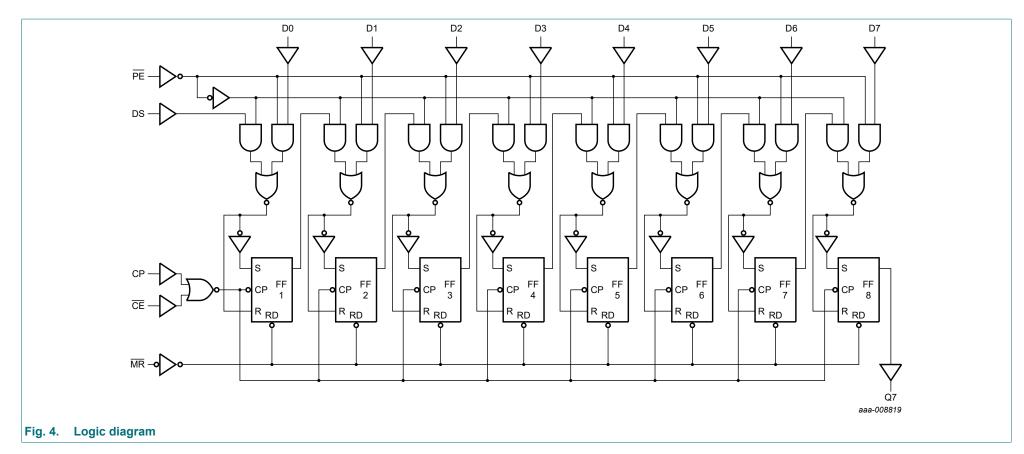
### 4. Functional diagram



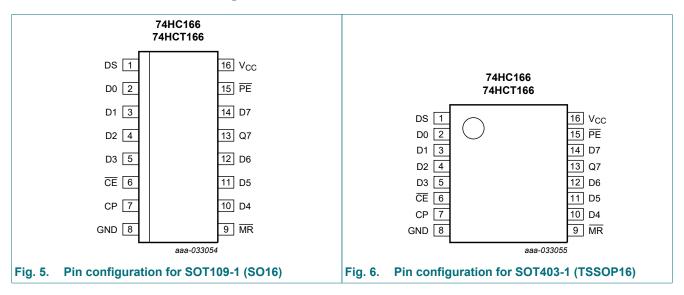
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### 74HC166-Q100; 74HCT166-Q100

8-bit parallel-in/serial out shift register



### 5. Pinning information



### 5.1. Pinning

### 5.2. Pin description

Symbol	Pin	Description
DS	1	serial data input
D0 to D7	2, 3, 4, 5, 10, 11, 12, 14	parallel data inputs
CE	6	clock enable input (active LOW)
СР	7	clock input (LOW-to-HIGH edge-triggered)
GND	8	ground (0 V)
MR	9	asynchronous master reset (active LOW)
Q7	13	serial output from the last stage
PE	15	parallel enable input (active LOW)
V <sub>CC</sub>	16	positive supply voltage

### 6. Functional description

#### Table 3. Function table

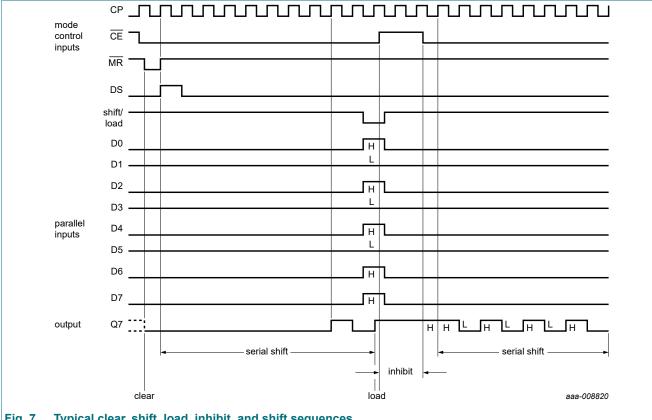
H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

L = LOW voltage level; I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

*q* = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

 $X = don't care; \uparrow = LOW-to-HIGH clock transition.$ 

Operating modes	Inputs					Qn register	Output	
	PE	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7
parallel load	I	I	1	Х	I	L	L to L	L
	I	I	1	Х	h	Н	H to H	Н
serial shift	h	I	1	I	Х	L	q0 to q5	q6
	h	I	1	h	Х	Н	q0 to q5	q6
hold "do nothing"	Х	Н	Х	Х	Х	q0	q1 to q6	q7



Typical clear, shift, load, inhibit, and shift sequences Fig. 7.

### 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
lo	output current	$-0.5 V < V_O < V_{CC} + 0.5 V$		-	±25	mA
I <sub>CC</sub>	supply current			-	50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	[2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT109-1 (SO16) package:  $P_{tot}$  derates linearly with 12.4 mW/K above 110 °C.

For SOT403-1 (TSSOP16) package: Ptot derates linearly with 8.5 mW/K above 91 °C.

### 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	onditions 74HC166-Q100			74H	2100	Unit	
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V

### 9. Static characteristics

#### Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC16	6-Q100									
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V

### 8-bit parallel-in/serial out shift register

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Мах	Min	Max	
V <sub>OH</sub>	HIGH-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH}$ or $V_{IL}$								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±0.1	-	±1	-	±1	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	-	80	-	160	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT1	66-Q100								•	
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 V$								
	output voltage	I <sub>O</sub> = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 V$								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 4.5 V	-	0.16	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 4.5 V$	-	-	±0.1	-	±1	-	±1	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC} \text{ or GND}; I_O = 0 \text{ A};$ $V_{CC} = 4.5 \text{ V}$	-	-	8.0	-	80	-	160	μA
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V};$ other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V								
		Dn and DS inputs	-	35	126	-	157.5	-	171.5	μA
		CP and CE inputs	-	80	288	-	360	-	392	μA
		MR input	-	40	144	-	180	-	196	μA
		PE input	-	60	216	-	270	-	294	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

### **10.** Dynamic characteristics

#### Table 7. Dynamic characteristics

GND (ground = 0 V);  $t_r = t_f = 6$  ns:  $C_L = 50$  pF unless otherwise specified; for test circuit, see Fig. 11

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	1
74HC16	6-Q100								_	
t <sub>pd</sub>	propagation	CP to Q7; see Fig. 8 [1]								
delay	delay	V <sub>CC</sub> = 2.0 V	-	50	150	-	190	-	225	ns
		V <sub>CC</sub> = 4.5 V	-	18	30	-	38	-	45	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	15	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	14	26	-	33	-	38	ns
		MR to Q7; see Fig. 9								
		V <sub>CC</sub> = 2.0 V	-	47	160	-	200	-	240	ns
		V <sub>CC</sub> = 4.5 V	-	17	32	-	40	-	48	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	14	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	14	27	-	34	-	41	ns
t <sub>t</sub>	transition	output; see Fig. 8 [2]								
	time	V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns
t <sub>W</sub>	pulse width	CP input HIGH or LOW; see <u>Fig. 8</u>								
		V <sub>CC</sub> = 2.0 V	80	17	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	5	-	17	-	20	-	ns
		MR input LOW; see Fig. 9								
		V <sub>CC</sub> = 2.0 V	100	25	-	125	-	150	-	ns
		V <sub>CC</sub> = 4.5 V	20	9	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	7	-	21	-	26	-	ns
t <sub>rec</sub>	recovery	MR to CP; see Fig. 9								
	time	V <sub>CC</sub> = 2.0 V	0	-19	-	0	-	0	-	ns
		V <sub>CC</sub> = 4.5 V	0	-7	-	0	-	0	-	ns
		V <sub>CC</sub> = 6.0 V	0	-6	-	0	-	0	-	ns
t <sub>su</sub>	set-up time	Dn, CE to CP; see Fig. 10								
		V <sub>CC</sub> = 2.0 V	80	14	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	5	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	4	-	17	-	20	-	ns
		PE to CP; see Fig. 10								
		V <sub>CC</sub> = 2.0 V	100	33	-	125	-	150	-	ns
		V <sub>CC</sub> = 4.5 V	20	12	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	10	-	21	-	26	-	ns

### 8-bit parallel-in/serial out shift register

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>h</sub>	hold time	Dn, CE to CP; see Fig. 10								
		V <sub>CC</sub> = 2.0 V	2	-8	-	2	-	2	-	ns
		V <sub>CC</sub> = 4.5 V	2	-3	-	2	-	2	-	ns
		V <sub>CC</sub> = 6.0 V	2	-2	-	2	-	2	-	ns
		PE to CP; see Fig. 10								
		V <sub>CC</sub> = 2.0 V	0	-28	-	0	-	0	-	ns
		V <sub>CC</sub> = 4.5 V	0	-10	-	0	-	0	-	ns
		V <sub>CC</sub> = 6.0 V	0	-8	-	0	-	0	-	ns
f <sub>max</sub>	maximum	CP input; see <u>Fig. 8</u>								
	frequency	V <sub>CC</sub> = 2.0 V	6	19	-	4.8	-	4	-	MHz
		V <sub>CC</sub> = 4.5 V	30	57	-	24	-	20	-	MHz
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	63	-	-	-	-	-	MHz
		V <sub>CC</sub> = 6.0 V	35	68	-	28	-	24	-	MHz
C <sub>PD</sub>	power dissipation capacitance	per package; [3 V <sub>I</sub> = GND to V <sub>CC</sub>	- []	41	-	-	-	-	-	pF
74HCT1	66-Q100						1	1	1	1
t <sub>pd</sub>	propagation	CP to Q7; see Fig. 8 [1	]							
	delay	V <sub>CC</sub> = 4.5 V	-	23	40	-	50	-	60	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	20	-	-	-	-	-	ns
		MR to Q7; see Fig. 9								
		V <sub>CC</sub> = 4.5 V	-	22	40	-	50	-	60	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	19	-	-	-	-	-	ns
t <sub>t</sub>	transition	output; see Fig. 8 [2	]							
	time	V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
t <sub>W</sub>	pulse width	CP input HIGH or LOW; see <u>Fig. 8</u>								
		V <sub>CC</sub> = 4.5 V	20	9	-	25	-	30	-	ns
		MR input LOW; see Fig. 9								
		V <sub>CC</sub> = 4.5 V	25	11	-	31	-	38	-	ns
t <sub>rec</sub>	recovery	MR to CP; see Fig. 9								
	time	V <sub>CC</sub> = 4.5 V	0	-7	-	0	-	0	-	ns
t <sub>su</sub>	set-up time	Dn, CE to CP; see Fig. 10								
		V <sub>CC</sub> = 4.5 V	16	8	-	20	-	24	-	ns
		PE to CP; see Fig. 10								
		V <sub>CC</sub> = 4.5 V	30	15	-	38	-	45	-	ns
t <sub>h</sub>	hold time	Dn, CE to CP; see Fig. 10								
		V <sub>CC</sub> = 4.5 V	0	-3	-	0	-	0	-	ns
		PE to CP; see Fig. 10								
		V <sub>CC</sub> = 4.5 V	0	-13	-	0	-	0	-	ns
f <sub>max</sub>	maximum	CP input; see <u>Fig. 8</u>								
	frequency	V <sub>CC</sub> = 4.5 V	25	45	-	20	-	17	-	MHz
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	50	-	-	-	-	_	MHz

#### 8-bit parallel-in/serial out shift register

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Тур	Мах	Min	Max	Min	Мах	
C <sub>PD</sub>		per package; [3] $V_I = GND$ to $V_{CC} - 1.5 V$	-	41	-	-	-	-	-	pF

[1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

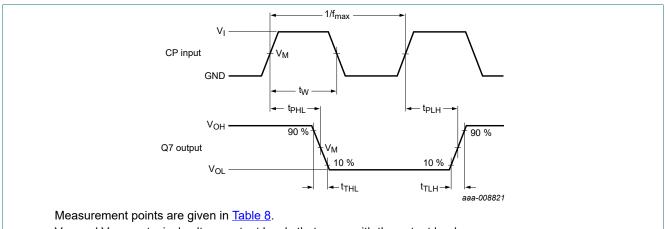
 $f_o = output$  frequency in MHz;

 $\Sigma$  (C<sub>L</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>o</sub>) = sum of outputs;

 $C_L$  = output load capacitance in pF;

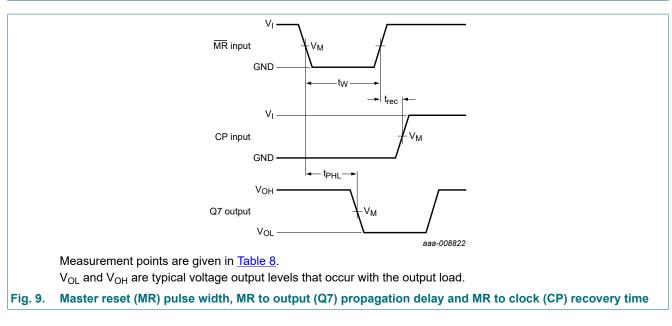
 $V_{CC}$  = supply voltage in V.

### 10.1. Waveforms and test circuit

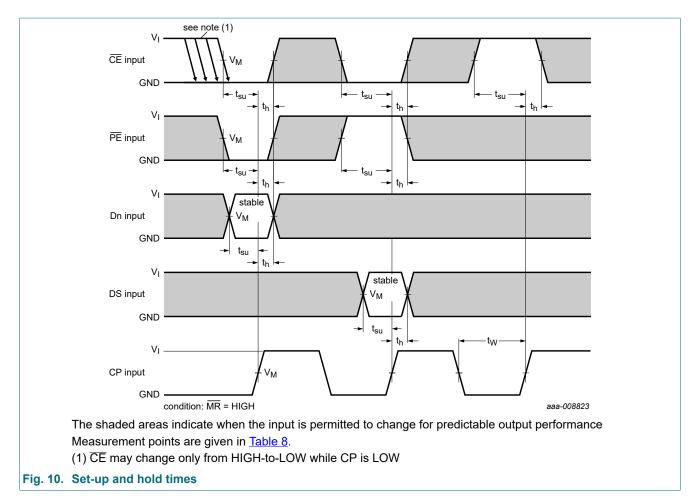


 $V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.





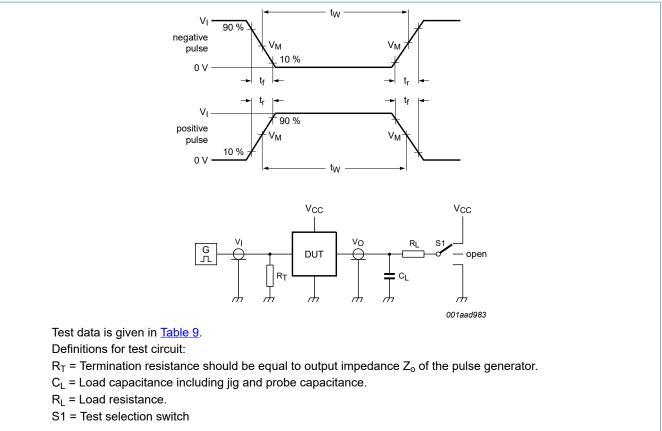
### 8-bit parallel-in/serial out shift register



#### Table 8. Measurement points

Туре	Input		Output
	VI	V <sub>M</sub>	V <sub>M</sub>
74HC166-Q100	V <sub>CC</sub>	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
74HCT166-Q100	3 V	1.3 V	1.3 V

### 8-bit parallel-in/serial out shift register

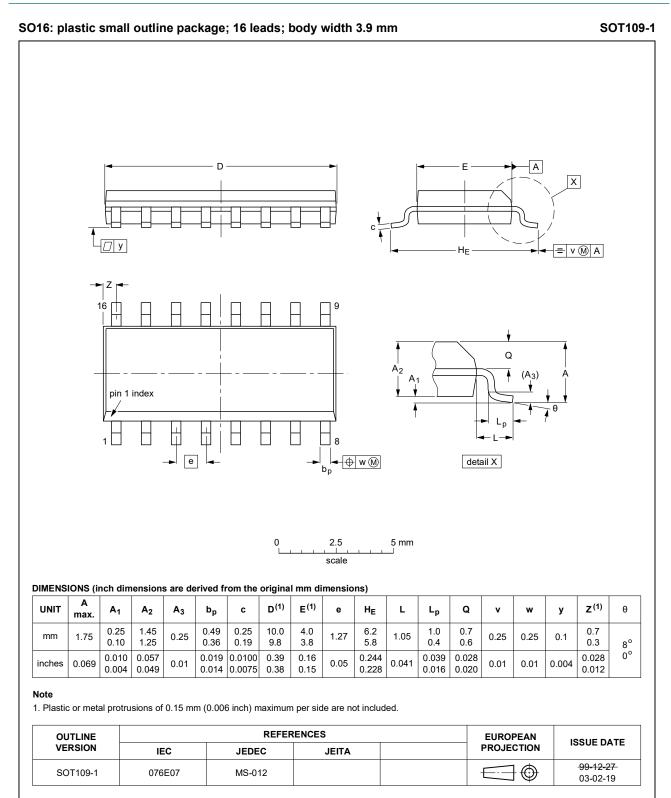


#### Fig. 11. Test circuit for measuring switching times

#### Table 9. Test data

Туре	Input		Load		S1 position
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHL</sub> , t <sub>PLH</sub>
74HC166-Q100	V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	open
74HCT166-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open

### **11. Package outline**



#### Fig. 12. Package outline SOT109-1 (SO16)

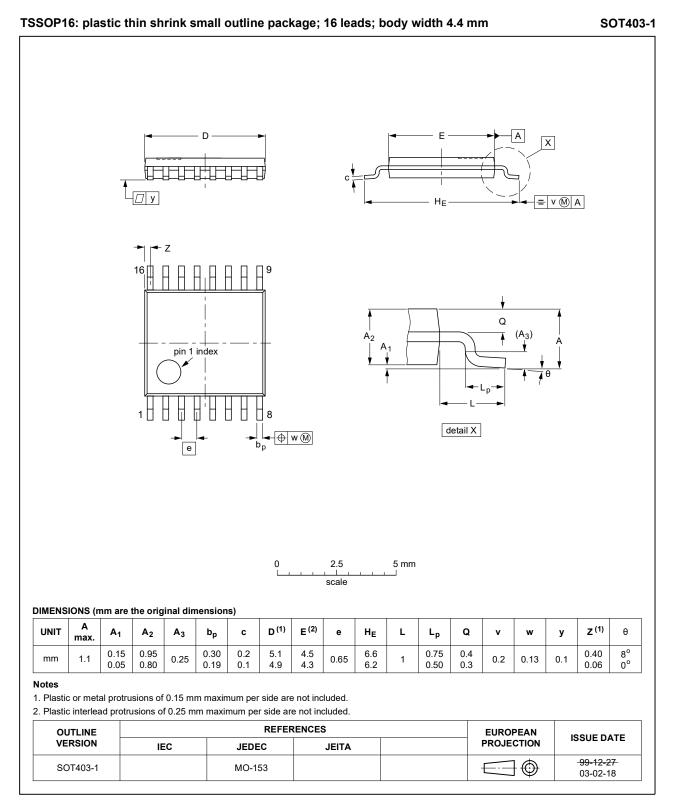


Fig. 13. Package outline SOT403-1 (TSSOP16)

<sup>74</sup>HC\_HCT166\_Q100

### 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

### 13. Revision history

Table 11. Revision history							
Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC_HCT166_Q100 v.2	20210809	Product data sheet	-	74HC_HCT166_Q100 v.1			
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li><u>Section 2</u> updated.</li> <li><u>Section 7</u>: Derating values for P<sub>tot</sub> total power dissipation have been updated.</li> </ul>						
74HC_HCT166_Q100 v.1	20130925	Product data sheet	-	-			

### 14. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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#### 8-bit parallel-in/serial out shift register

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